

Green Products

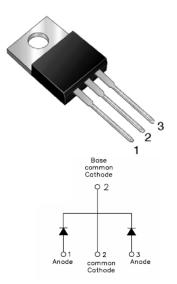
SBR10100CT SCHOTTKY RECTIFIER

Applications:

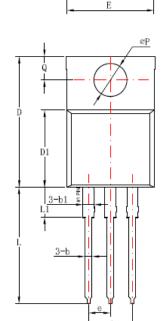
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

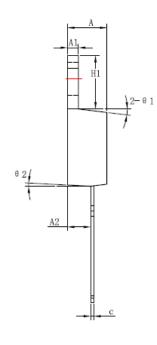
Features:

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions (In mm / Inches) and Marking:





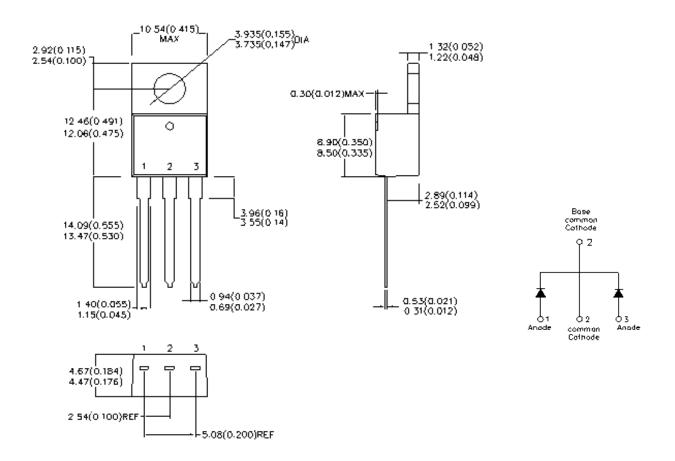
	Dimensions in			
Symbol	millimeters			
	Min	Typical	Max	
Α	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
Е	10.01	10.16	10.31	
е		2.54		
e1		5.06		
H1	6.04	6.24	6.44	
L	12.7	13.56	13.78	
L1		3.5		
ФР	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4°		

OPTION1 (HD)

- China Germany Korea Singapore United States
 - http://www.smc-diodes.comsales@ smc-diodes.com



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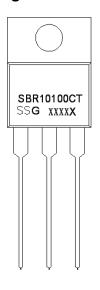
OPTION2 (CJ)

TO-220AB



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Marking Diagram:



Where XXXXX is YYWWL

SBR = Device Type

10 = Forward Current (10A) 100 = Reverse Voltage (100V)

CT = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SBR10100CT	TO-220AB (Pb-Free)	50 pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	100	V
Average Forward Current (per device)	I _{F(AV)}	50% duty cycle @T _C = 150°C, rectangular wave form	10	Α
Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	120	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop (per leg) *	V_{F1}	@ 5 A, Pulse, T_C = 25 °C	0.88	V
	V_{F2}	@ 5 A, Pulse, T _C = 125 °C	0.75	V
Reverse Current (per leg) *	I _{R1}	$@V_R = \text{rated } V_R$ $T_C = 25 ^{\circ}\text{C}$	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_C = 125 ^{\circ}C$	15.0	mA
Repetitive peak reverse current	IRRM	tp = 2 μs square F= 1 kHz	1	A
Non-Repetitive Avalanche Energy	Eas	T _J = 25°C, I _{AS} = 5 A, L = 1mH	12.5	mJ
Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25^{\circ}C$ $f_{SIG} = 1MHz$	300	pF

Pulse Width < 300μs, Duty Cycle <2%

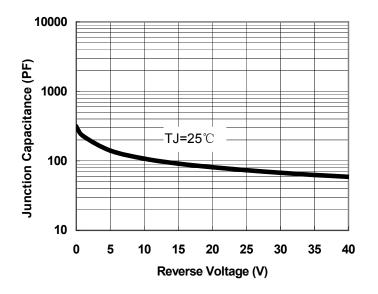
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +200	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal	В	DC operation	3.5	°C/W
Resistance Junction to Case	$R_{\theta JC}$	DC operation	3.5	-0/00
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			

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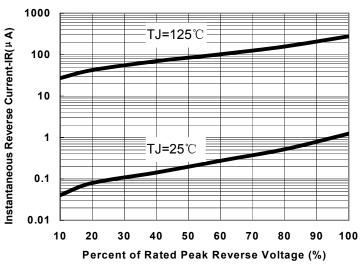


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

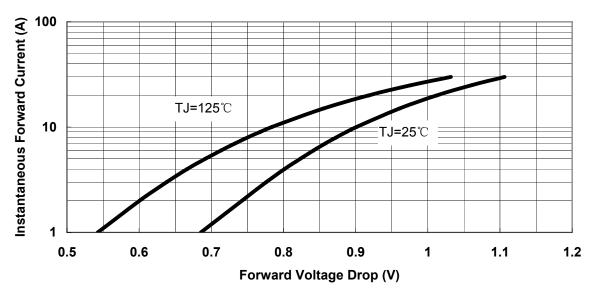
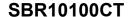


Fig.3-Typical Instantaneous Forward Voltage Characteristics





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